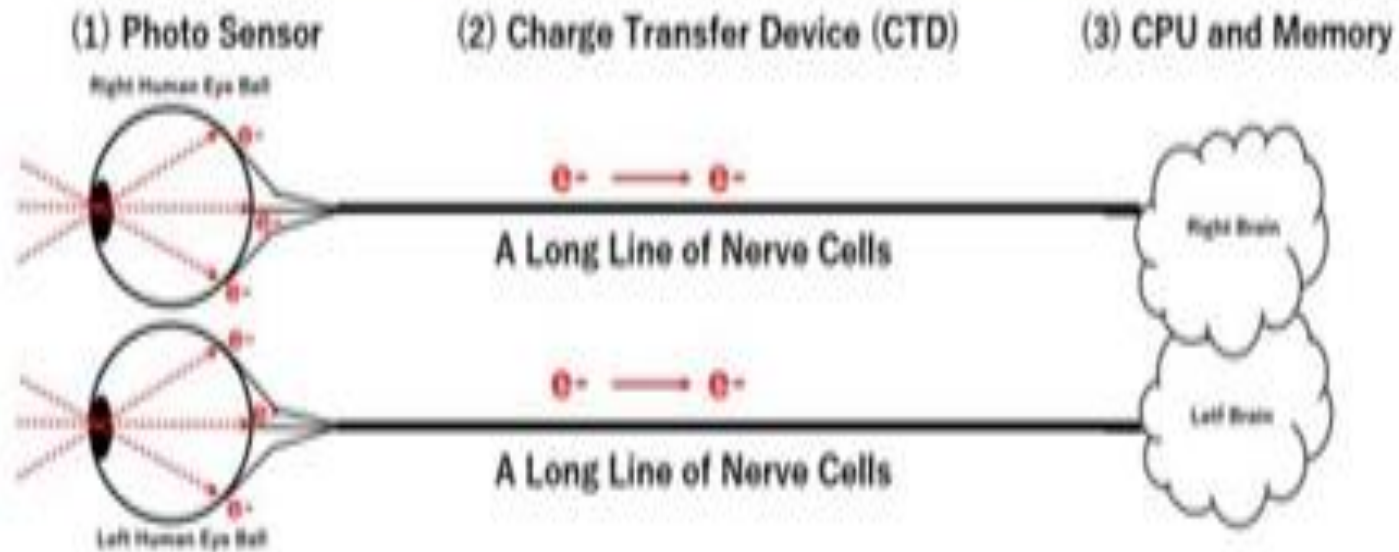


# Three important parts of Image Sensor



## History of Charge Transfer Device (CTD)

- (1) 1T1C DRAM Cell type MOS Image Sensor
- (2) CCD/MOS Capacitor type Image Sensor
- (3) CMOS Digital Circuit type Image Sensor

受光面がピン留めされた Double Junction Type New Solar Cell の提案

See JPA2020-131313 invented by Yoshiaki Hagiwara (AIPS) in 2020